



Low Power, 12.65 mW, 2.3 V to 5.5 V, Programmable Waveform Generator

Enhanced Product

AD9833-EP

FEATURES

- Digitally programmable frequency and phase
- 12.65 mW power consumption at 3 V
- 0 MHz to 12.5 MHz output frequency range
- 28-bit resolution: 0.1 Hz at 25 MHz reference clock
- Sinusoidal, triangular, and square wave outputs
- 2.3 V to 5.5 V power supply
- No external components required
- 3-wire SPI interface
- Power-down option
- 10-lead MSOP package
- Enhanced product features
 - Supports defense and aerospace applications (AQEC)
 - Temperature range: -55°C to $+125^{\circ}\text{C}$
 - Controlled manufacturing baseline
 - 1 assembly/test site
 - 1 fabrication site
 - Enhanced product change notification
 - Qualification data available upon request

APPLICATIONS

- Frequency stimulus/waveform generation
- Liquid and gas flow measurement
- Sensory applications: proximity, motion, defect detection
- Line loss/attenuation
- Test and medical equipment
- Sweep/clock generators
- Time domain reflectometry (TDR) applications

GENERAL DESCRIPTION

The [AD9833-EP](#) is a low power, programmable waveform generator capable of producing sine, triangular, and square wave outputs. Waveform generation is required in various types of sensing, actuation, and time domain reflectometry (TDR) applications. The output frequency and phase are software programmable, allowing easy tuning. No external components are needed. The frequency registers are 28 bits wide. With a 25 MHz clock rate, a resolution of 0.1 Hz can be achieved; with a 1 MHz clock rate, the [AD9833-EP](#) can be tuned to 0.004 Hz resolution.

The [AD9833-EP](#) is written to via a 3-wire serial interface. This serial interface operates at clock rates up to 40 MHz and is compatible with DSP and microcontroller standards. The device operates with a power supply from 2.3 V to 5.5 V.

The [AD9833-EP](#) has a power-down function (SLEEP). This function allows sections of the device that are not being used to be powered down, thus minimizing the current consumption of the part. For example, the DAC can be powered down when a clock output is being generated.

The [AD9833-EP](#) is available in a 10-lead MSOP package. Additional application and technical information can be found in the [AD9833](#) data sheet.

FUNCTIONAL BLOCK DIAGRAM

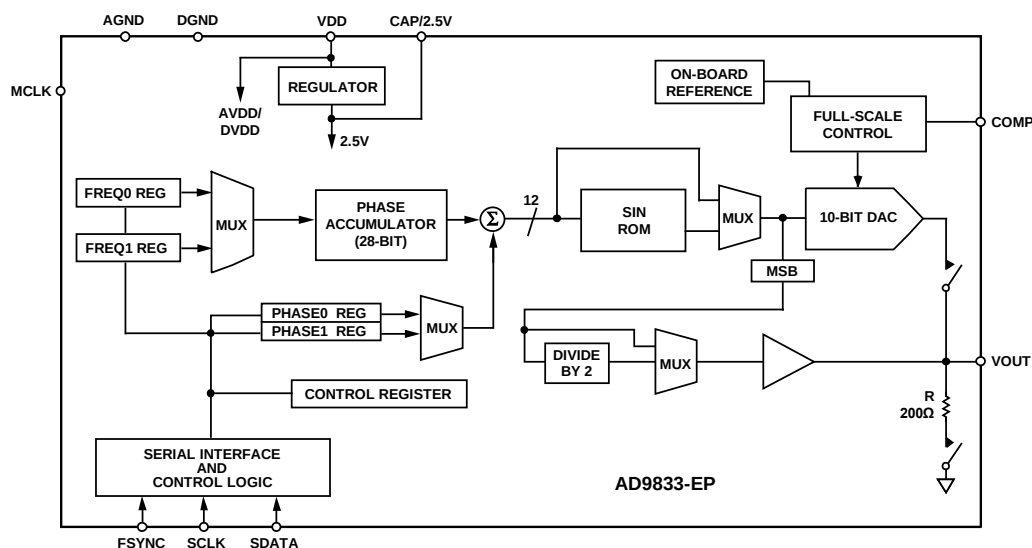


Figure 1.

Rev. 0

Document Feedback

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REVISION HISTORY

8/13—Revision 0: Initial Version

SPECIFICATIONS

VDD = 2.3 V to 5.5 V, AGND = DGND = 0 V, $T_A = T_{MIN}$ to T_{MAX} , $R_{SET} = 6.8\text{ k}\Omega$ for VOUT, unless otherwise noted.

Table 1.

Parameter ¹	Min	Typ	Max	Unit	Test Conditions/Comments
SIGNAL DAC SPECIFICATIONS					
Resolution		10		Bits	
Update Rate			25	MSPS	
VOUT Maximum		0.65		V	
VOUT Minimum		38		mV	
VOUT Temperature Coefficient		200		ppm/°C	
DC Accuracy					
Integral Nonlinearity		±1.0		LSB	
Differential Nonlinearity		±0.5		LSB	
DDS SPECIFICATIONS (SFDR)					
Dynamic Specifications					
Signal-to-Noise Ratio (SNR)	53.5	60		dB	$f_{MCLK} = 25\text{ MHz}$, $f_{OUT} = f_{MCLK}/4096$
Total Harmonic Distortion (THD)		−66	−53.5	dBc	$f_{MCLK} = 25\text{ MHz}$, $f_{OUT} = f_{MCLK}/4096$
Spurious-Free Dynamic Range (SFDR)					
Wideband (0 to Nyquist)		−60		dBc	$f_{MCLK} = 25\text{ MHz}$, $f_{OUT} = f_{MCLK}/50$
Narrow-Band (±200 kHz)		−78		dBc	$f_{MCLK} = 25\text{ MHz}$, $f_{OUT} = f_{MCLK}/50$
Clock Feedthrough		−60		dBc	
Wake-Up Time		1		ms	
LOGIC INPUTS					
Input High Voltage, V_{INH}	1.7			V	2.3 V to 2.7 V power supply
	2.0			V	2.7 V to 3.6 V power supply
	2.8			V	4.5 V to 5.5 V power supply
Input Low Voltage, V_{INL}			0.5	V	2.3 V to 2.7 V power supply
			0.7	V	2.7 V to 3.6 V power supply
			0.8	V	4.5 V to 5.5 V power supply
Input Current, I_{INH}/I_{INL}			10	μA	
Input Capacitance, C_{IN}		3		pF	
POWER SUPPLIES					
VDD	2.3		5.5	V	$f_{MCLK} = 25\text{ MHz}$, $f_{OUT} = f_{MCLK}/4096$
I_{DD}		4.5	5.5	mA	I_{DD} code dependent; see Figure 7
Low Power Sleep Mode		0.5		mA	DAC powered down, MCLK running

¹ Operating temperature range is −55°C to +125°C; typical specifications are at 25°C.

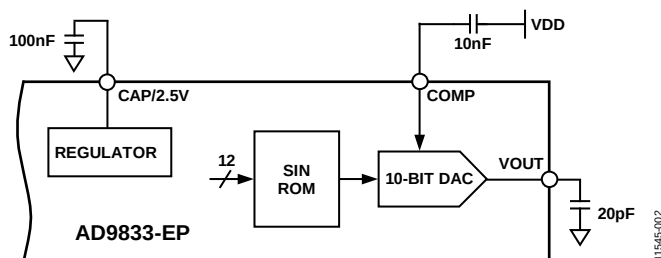


Figure 2. Test Circuit Used to Test Specifications

TIMING CHARACTERISTICS

VDD = 2.3 V to 5.5 V, AGND = DGND = 0 V, unless otherwise noted.¹

Table 2.

Parameter	Limit at T _{MIN} to T _{MAX}	Unit	Description
t ₁	40	ns min	MCLK period
t ₂	16	ns min	MCLK high duration
t ₃	16	ns min	MCLK low duration
t ₄	25	ns min	SCLK period
t ₅	10	ns min	SCLK high duration
t ₆	10	ns min	SCLK low duration
t ₇	5	ns min	FSYNC to SCLK falling edge setup time
t _{8 min}	10	ns min	FSYNC to SCLK hold time
t _{8 max}	t ₄ - 5	ns max	
t ₉	5	ns min	Data setup time
t ₁₀	3	ns min	Data hold time
t ₁₁	5	ns min	SCLK high to FSYNC falling edge setup time

¹ Guaranteed by design, not production tested.

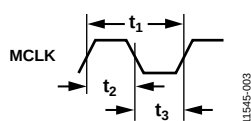
Timing Diagrams

Figure 3. Master Clock

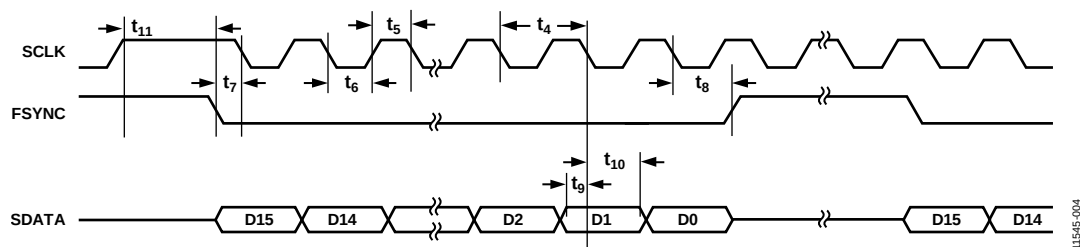


Figure 4. Serial Timing

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 3.

Parameter	Rating
VDD to AGND	$-0.3\text{ V to }+6\text{ V}$
VDD to DGND	$-0.3\text{ V to }+6\text{ V}$
AGND to DGND	$-0.3\text{ V to }+0.3\text{ V}$
CAP/2.5V	2.75 V
Digital I/O Voltage to DGND	$-0.3\text{ V to VDD} + 0.3\text{ V}$
Analog I/O Voltage to AGND	$-0.3\text{ V to VDD} + 0.3\text{ V}$
Operating Temperature Range	$-55^\circ\text{C to }+125^\circ\text{C}$
Storage Temperature Range	$-65^\circ\text{C to }+150^\circ\text{C}$
Maximum Junction Temperature	150°C
MSOP Package	
θ_{JA} Thermal Impedance	206°C/W
θ_{JC} Thermal Impedance	44°C/W
Lead Temperature, Soldering (10 sec)	300°C
IR Reflow, Peak Temperature	220°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

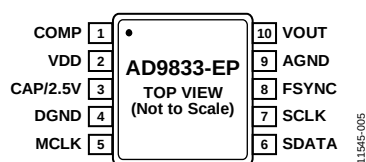


Figure 5. Pin Configuration

Table 4. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	COMP	DAC Bias Pin. This pin is used for decoupling the DAC bias voltage.
2	VDD	Positive Power Supply for the Analog and Digital Interface Sections. The on-board 2.5 V regulator is also supplied from VDD. VDD can have a value from 2.3 V to 5.5 V. A 0.1 μ F and a 10 μ F decoupling capacitor should be connected between VDD and AGND.
3	CAP/2.5V	The digital circuitry operates from a 2.5 V power supply. This 2.5 V is generated from VDD using an on-board regulator when VDD exceeds 2.7 V. The regulator requires a decoupling capacitor of 100 nF typical, which is connected from CAP/2.5V to DGND. If VDD is less than or equal to 2.7 V, CAP/2.5V should be tied directly to VDD.
4	DGND	Digital Ground.
5	MCLK	Digital Clock Input. DDS output frequencies are expressed as a binary fraction of the frequency of MCLK. The output frequency accuracy and phase noise are determined by this clock.
6	SDATA	Serial Data Input. The 16-bit serial data-word is applied to this input.
7	SCLK	Serial Clock Input. Data is clocked into the AD9833-EP on each falling edge of SCLK.
8	FSYNC	Active Low Control Input. FSYNC is the frame synchronization signal for the input data. When FSYNC is taken low, the internal logic is informed that a new word is being loaded into the device.
9	AGND	Analog Ground.
10	VOUT	Voltage Output. The analog and digital output from the AD9833-EP is available at this pin. An external load resistor is not required because the device has a 200 Ω resistor on board.

TYPICAL PERFORMANCE CHARACTERISTICS

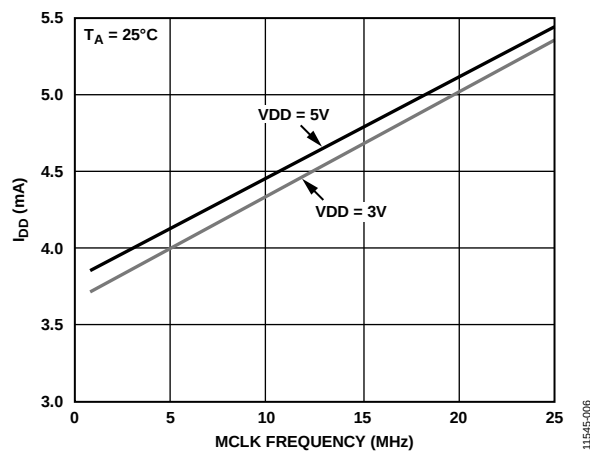


Figure 6. Typical Current Consumption (I_{DD}) vs. MCLK Frequency for $f_{OUT} = MCLK/10$

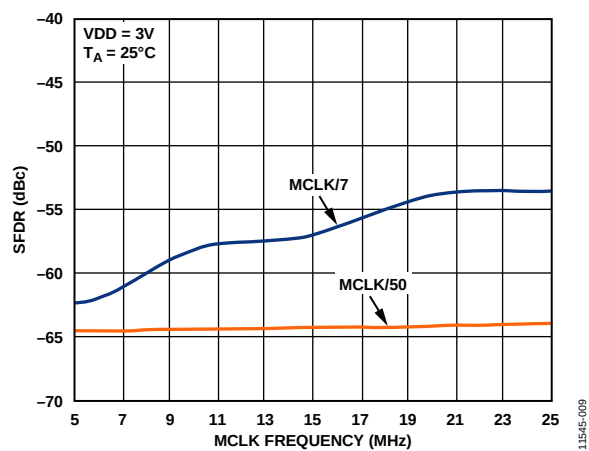


Figure 9. Wideband SFDR vs. MCLK Frequency

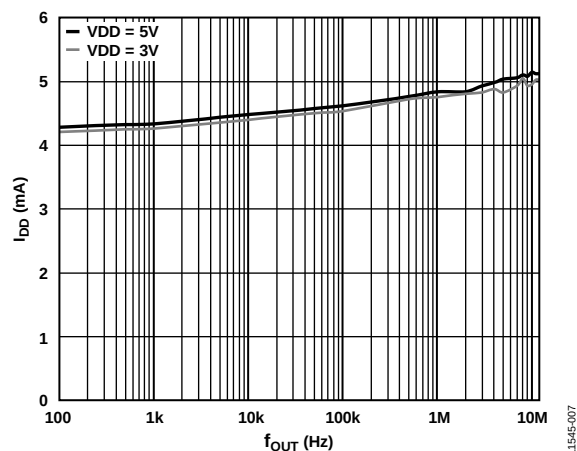


Figure 7. Typical I_{DD} vs. f_{OUT} for $f_{MCLK} = 25$ MHz

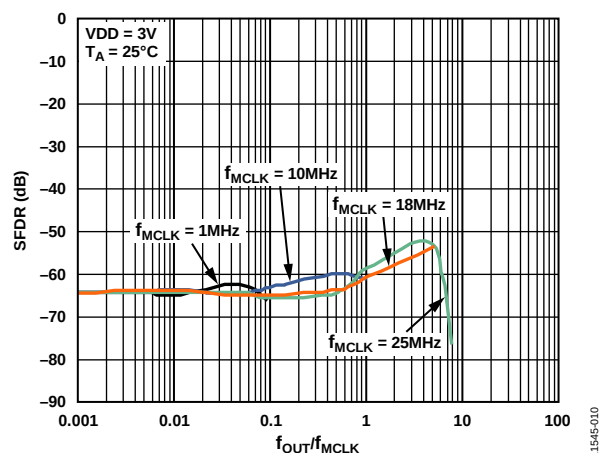


Figure 10. Wideband SFDR vs. f_{OUT}/f_{MCLK} for Various MCLK Frequencies

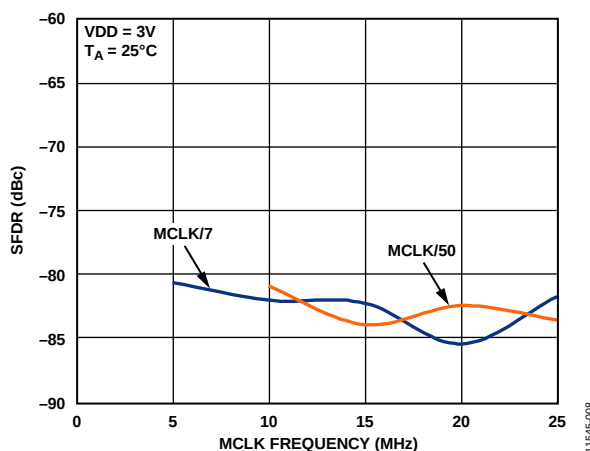


Figure 8. Narrow-Band SFDR vs. MCLK Frequency

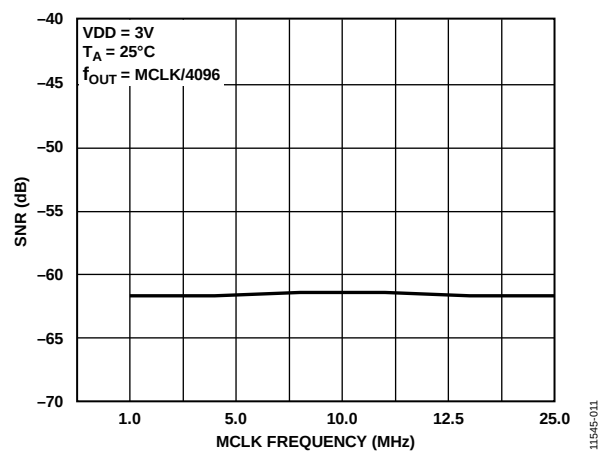


Figure 11. SNR vs. MCLK Frequency

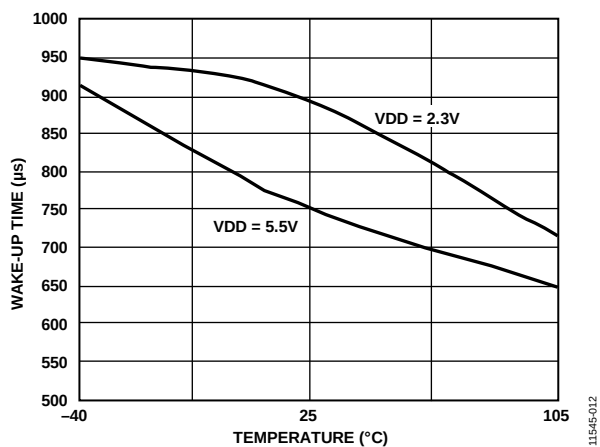


Figure 12. Wake-Up Time vs. Temperature

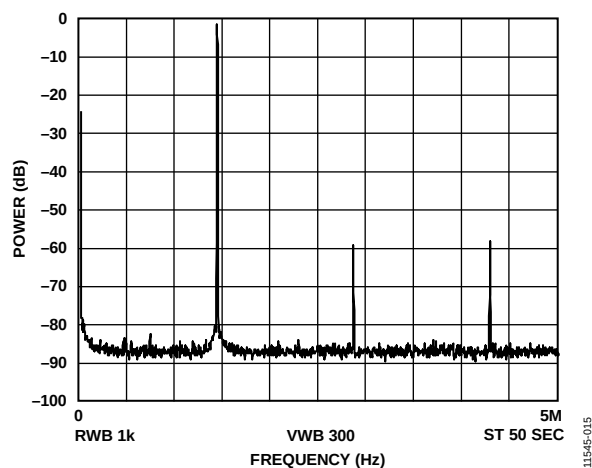


Figure 15. Power vs. Frequency, $f_{MCLK} = 10 \text{ MHz}$, $f_{OUT} = 1.43 \text{ MHz} = f_{MCLK}/7$, Frequency Word = 0x2492492

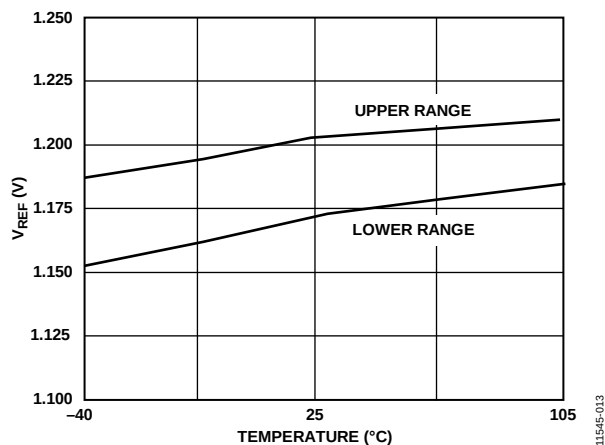


Figure 13. V_{REF} vs. Temperature

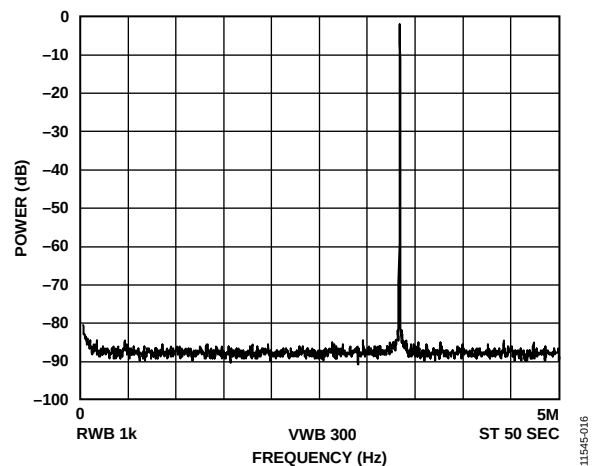


Figure 16. Power vs. Frequency, $f_{MCLK} = 10 \text{ MHz}$, $f_{OUT} = 3.33 \text{ MHz} = f_{MCLK}/3$, Frequency Word = 0x5555555

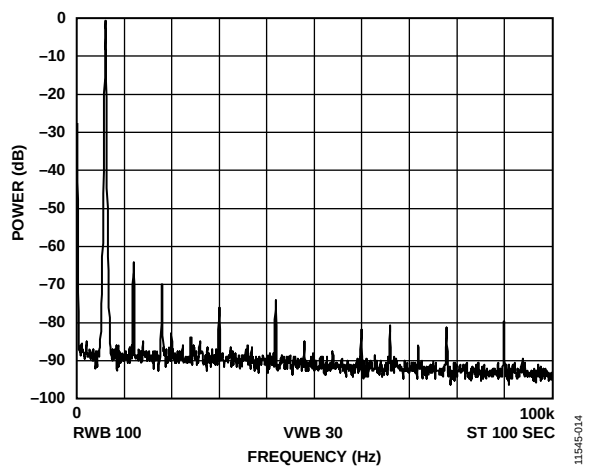


Figure 14. Power vs. Frequency, $f_{MCLK} = 10 \text{ MHz}$, $f_{OUT} = 2.4 \text{ kHz}$, Frequency Word = 0x000FBA9

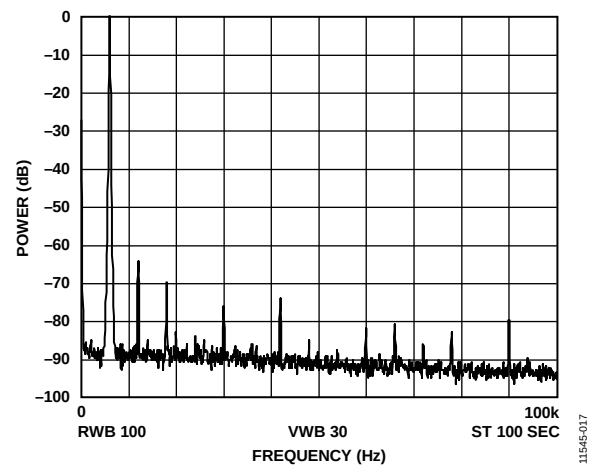


Figure 17. Power vs. Frequency, $f_{MCLK} = 25 \text{ MHz}$, $f_{OUT} = 6 \text{ kHz}$, Frequency Word = 0x000FBA9

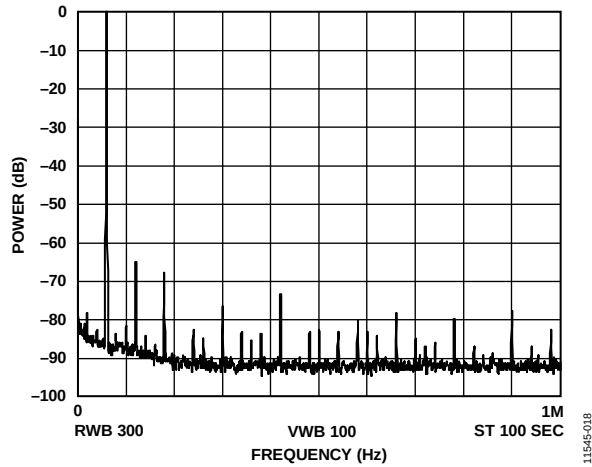


Figure 18. Power vs. Frequency, $f_{MCLK} = 25$ MHz, $f_{OUT} = 60$ kHz, Frequency Word = 0x009D495

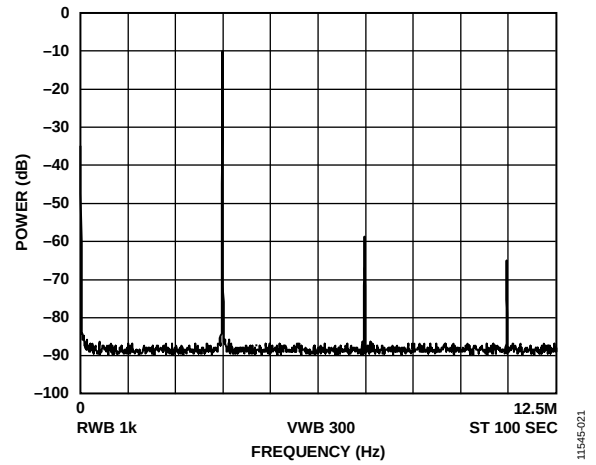


Figure 21. Power vs. Frequency, $f_{MCLK} = 25$ MHz, $f_{OUT} = 3.857$ MHz = $f_{MCLK}/7$, Frequency Word = 0x2492492

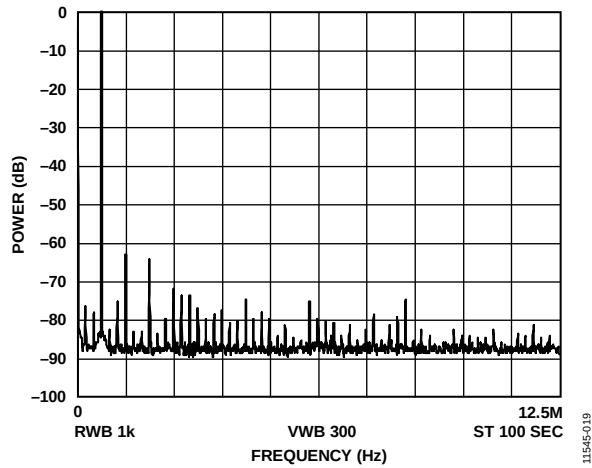


Figure 19. Power vs. Frequency, $f_{MCLK} = 25$ MHz, $f_{OUT} = 600$ kHz, Frequency Word = 0x0624DD3

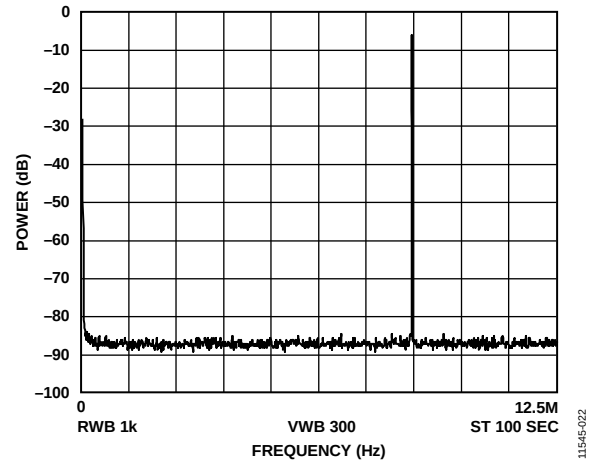


Figure 22. Power vs. Frequency, $f_{MCLK} = 25$ MHz, $f_{OUT} = 8.333$ MHz = $f_{MCLK}/3$, Frequency Word = 0x5555555

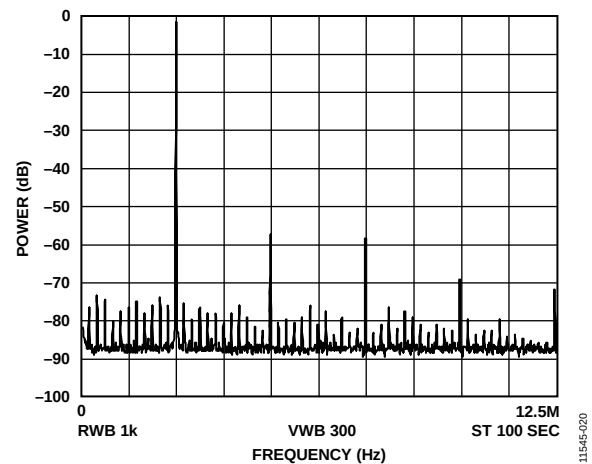


Figure 20. Power vs. Frequency, $f_{MCLK} = 25$ MHz, $f_{OUT} = 2.4$ MHz, Frequency Word = 0x189374D

OUTLINE DIMENSIONS

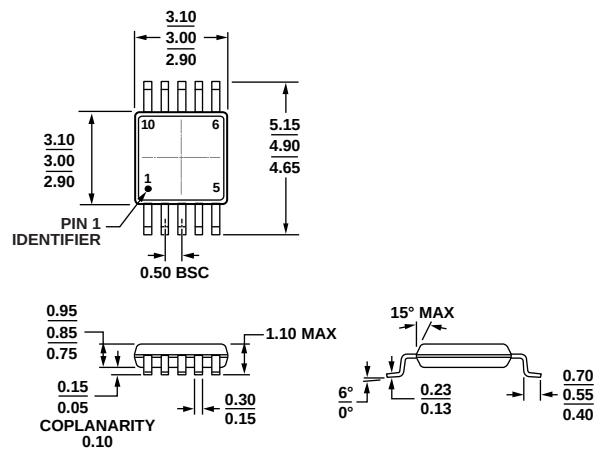


Figure 23. 10-Lead Mini Small Outline Package [MSOP]
(RM-10)
Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option	Branding
AD9833SRMZ-EP-RL7	–55°C to +125°C	10-Lead MSOP	RM-10	DMR

¹ Z = RoHS Compliant Part.

NOTES

NOTES